

## KSK30

### Low Noise PRE-AMP. Use

- High Input Impedance: I<sub>GSS</sub>=1nA (MAX)
  Low Noise: NF=0.5dB (TYP)
- High Voltage: V<sub>GDS</sub>= -50V



1. Source 2. Gate 3. Drain

### **Silicon N-channel Junction Fet**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>GDS</sub>	Gate-Drain Voltage	-50	V
I <sub>G</sub>	Gate-Current	10	mA
P <sub>D</sub>	Collector Dissipation	100	mW
T <sub>J</sub>	Junction Temperature	125	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 125	°C

### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter Test Condition		Min.	Тур.	Max.	Units	
$BV_{GDS}$	Gate-Drain Breakdown Voltage	V <sub>DS</sub> =0, I <sub>G</sub> = -100μA	-50			V	
I <sub>GSS</sub>	Gate Leak Current	$V_{GS}$ = -30V, $V_{DS}$ =0			-1	nA	
I <sub>DSS</sub>	Drain Leak Current	V <sub>DS</sub> =10V, V <sub>GS</sub> =0	0.3		6.5	mA	
V <sub>GS</sub> (off)	Gate-Source Voltage	V <sub>DS</sub> =10V, I <sub>D</sub> =0.1μA	-0.4		-5	V	
Y <sub>FS</sub>	Forward Transfer Admittance	V <sub>DS</sub> =10V, V <sub>GS</sub> =0, f=1KHz	1.2			mS	
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =0, V <sub>GS</sub> =0, f=1MHz		8.2		pF	
C <sub>RSS</sub>	Feedback Capacitance	V <sub>GD</sub> =10V, V <sub>DS</sub> =0 f=1MHz		2.6		pF	
NF	Noise Figure	$V_{DS}$ =15V, $V_{GS}$ =0 R <sub>G</sub> =100K $\Omega$ f=120Hz		0.5	5	dB	

## **I<sub>DSS</sub> Classification**

Classification	R	0	Y	G
I <sub>DSS</sub> (mA)	0.30 ~ 0.75	0.60 ~ 1.40	1.20 ~ 3.00	2.60 ~ 6.50

## **Typical Characteristics**

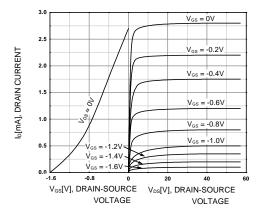


Figure 1. Static Characteristic

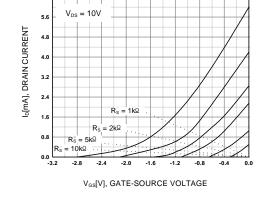


Figure 2. I<sub>D</sub>-V<sub>GS</sub>

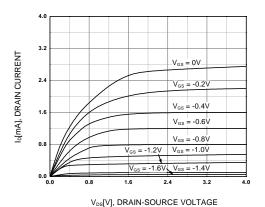


Figure 3.  $I_D$ - $V_{DS}$ 

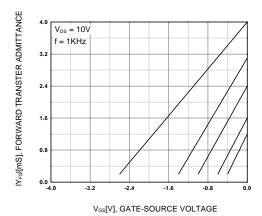


Figure 4. |Yfs|-V<sub>GS</sub>

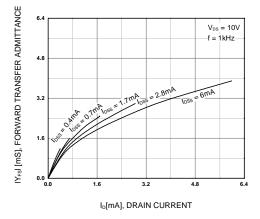


Figure 5. | Yfs |-I<sub>D</sub>

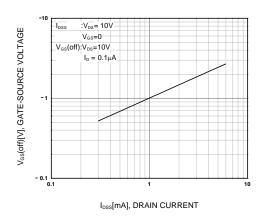


Figure 6. V<sub>GS</sub>(off)-I<sub>DSS</sub>

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## Typical Characteristics (Continued)

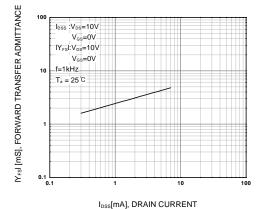
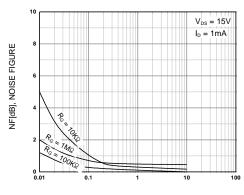


Figure 7. | Yfs | -I<sub>DSS</sub>



 $V_{\text{GS}}[V]$ , GATE-SOURCE VOLTAGE

Figure 8. NF-f

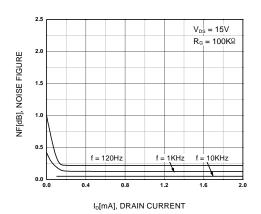


Figure 9. NF-I<sub>D</sub>

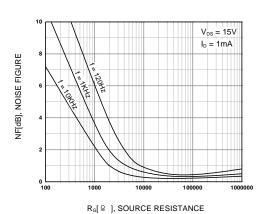


Figure 11. NF-R<sub>G</sub>



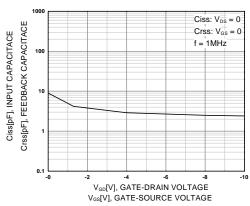


Figure 10. Ciss- $V_{GS}$ , Crss- $V_{GD}$ 

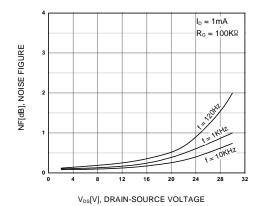


Figure 12. NF-V<sub>DS</sub>

# Typical Characteristics (Continued)

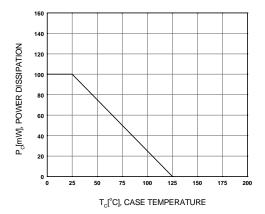
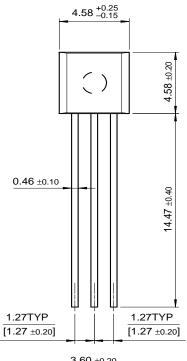


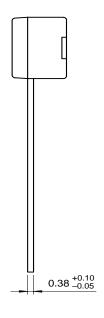
Figure 13. Power Derating

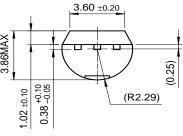
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## **Package Demensions**

TO-92







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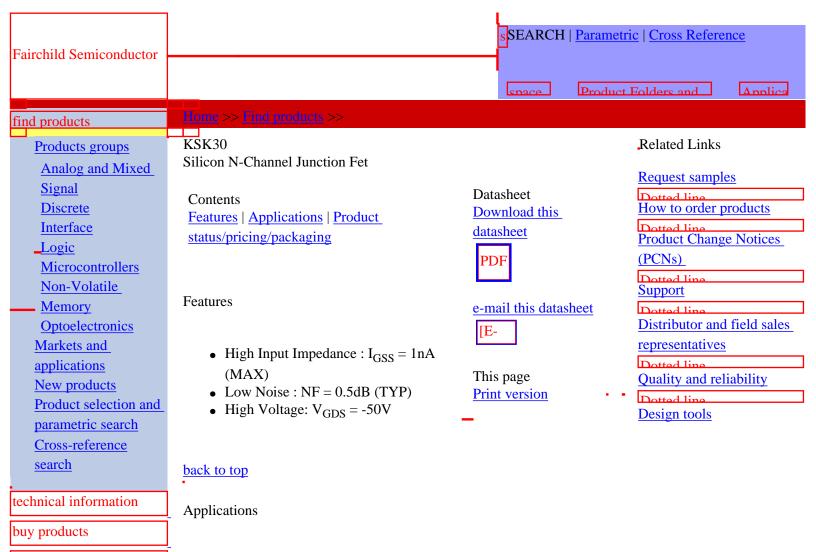
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### Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
KSK30YTA	Full Production	\$0.06	<u>TO-92</u>	3	TAPE REEL
KSK30GTA	Full Production	\$0.06	<u>TO-92</u>	3	TAPE REEL
KSK30YBU	Full Production	\$0.06	<u>TO-92</u>	3	BULK
KSK30OBU	Full Production	\$0.06	<u>TO-92</u>	3	BULK
KSK30GBU	Full Production	\$0.06	<u>TO-92</u>	3	BULK
KSK30RBU	Full Production	\$0.06	<u>TO-92</u>	3	BULK

<sup>\* 1,000</sup> piece Budgetary Pricing

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